

Features

- ◆ Bi-directional crowbar transient voltage protection
- ◆ High surge capability
- ◆ High off-state impedance
- ◆ Low leakage current
- ◆ Low on-state voltage
- ◆ Short-circuit failure mode
- ◆ Ultra Low Capacitance



DO-214AC(SMA)

Main Application

Sanyan's thyristor surge protector devices are designed to help protect sensitive telecommunication equipment from the hazards caused by lightning ,power contact,and power induction. These devices enable equipment to comply with various regulatory requirements including GR 1089,ITU K.20,K.21and K.45,IEC 60950,UL 60950,and TIA-968-A(formerly known as FCC Part 68).

Typical application including:

- Central office switching equipment. Analog and digital linecards(xDSL,T1/E1,ISDN.....)
- Customer Premises Equipment (CPE) such as phones, fax machines, modems, POS terminals, PBX systems and caller ID adjunct boxes.
- Primary protection modules including Main Distribution Frames(MDF),building entrance equipment and station protection modules.
- Access network equipment such as remote terminals,line repeaters,multiplexers,cross-connects,WAN equipment,Network Interface Devices(NID).
- Data lines and security systems.
- CATV line amplifiers and power inserters.
- Sprinkler systems.

Electrcal Parameters (Tamb=25°C)

Part Number	V _{DRM}	I _{DRM}	V _{BO}	I _{BO}	V _T	I _T	C _o	I _H
	Min.	Max.	Max.	Max.	Max.	Max.	Typ.	Min.
	V	uA	V	mA	V	A	pF	mA
P0080TB-MC	6	3	20	800	4	2.2	17	25

Part Number	V _{DRM}	I _{DRM}	V _{BO}	I _{BO}	V _T	I _T	C _o	I _H
	Min.	Max.	Max.	Max.	Max.	Max.	Max.	Min.
	V	uA	V	mA	V	A	pF	mA

Electrical Characteristics

V_{DRM} Stand-off voltage, is measured at I_{DRM}

V_{BO} Breakover voltage, is measured at 100V/ μ s.

C_o Off-state capacitance is measured in V_{DC}=2V@1MHz.

I_{DRM} Leakage current, is measured at V_{DRM}.

I_H Holding current.

I_{BO} Breakover current.

I_T ON-state current

V_T On-state voltage.

Electrical Characteristics Curves

Figure1 V-I Characteristics

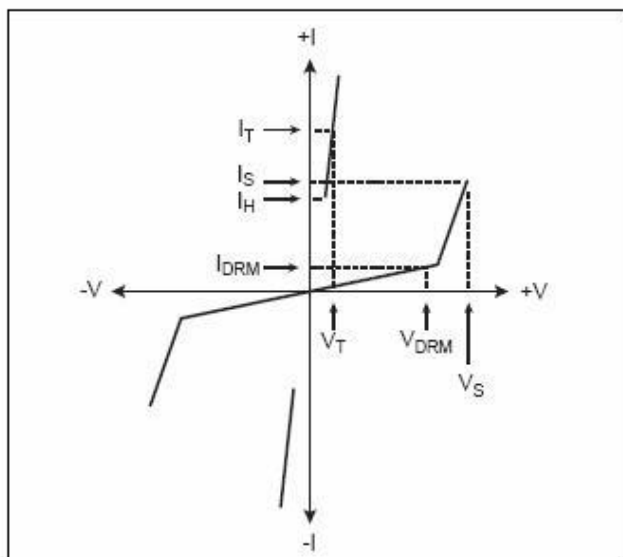


Figure2 tr x td Pulse Wave-form

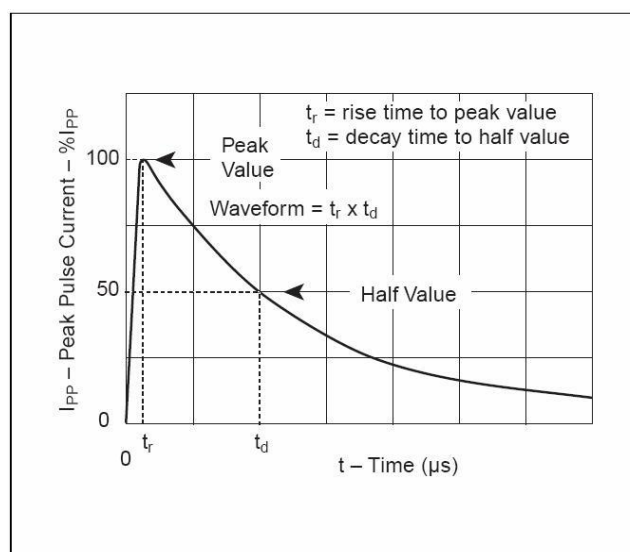


Figure Normalized V_S Change versus Junction Temperature

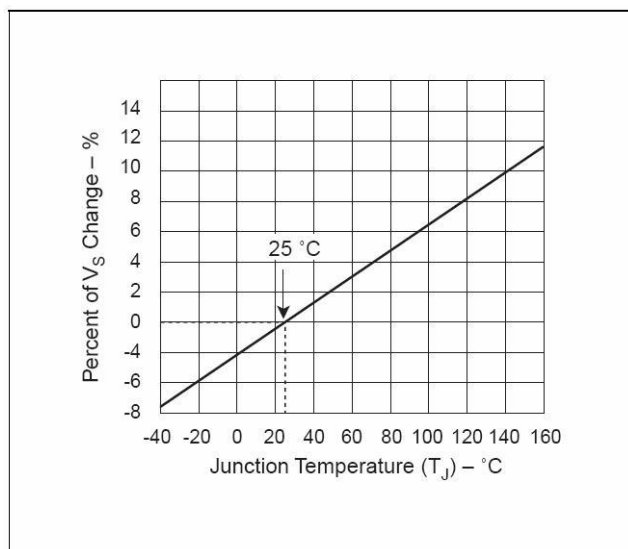
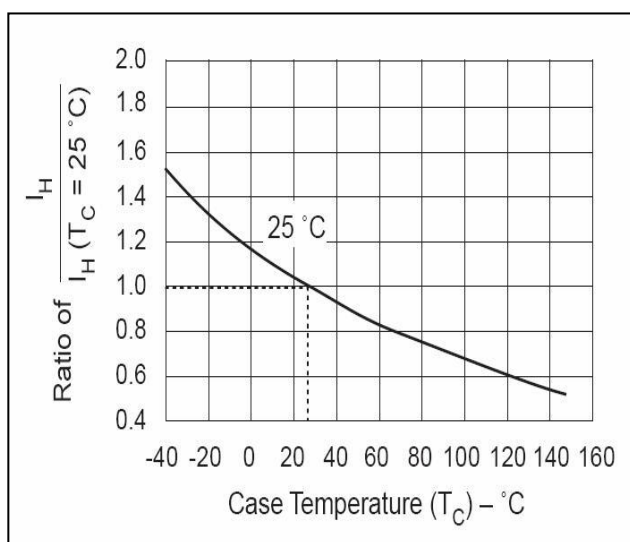


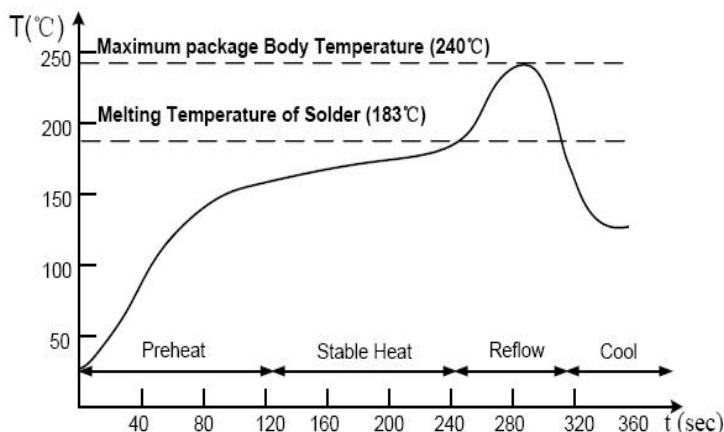
Figure 4 Normalized DC Holding Current



Thermal Considerations

Package	DO-214AC/SMA	Symbol	Parameter	Value	Unit
		T_J	Operating Junction Temperature	-40 to +150	°C
		T_S	Storage Temperature Range	-40 to +150	°C
		$R_{\theta JA}$	Junction to Ambient on printed circuit	90	°C/W

Solder Reflow Recommendations

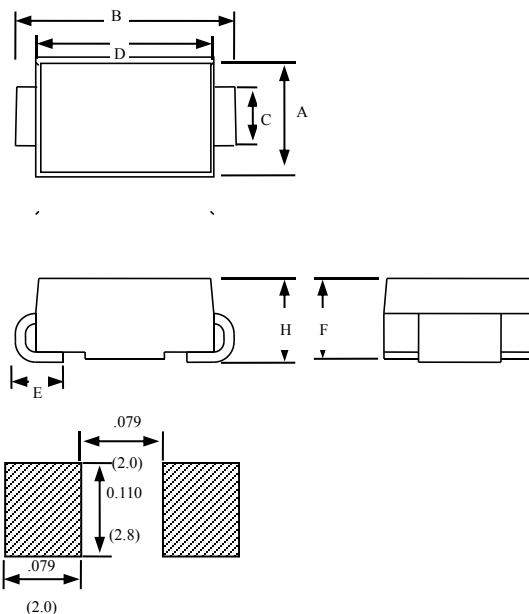


- Recommended reflow methods: IR, vapor phase oven, hot air oven, wave solder.
- The device can be exposed to a maximum temperature of 265°C for 10 seconds.
- Devices can be cleaned using standard industry methods and solvents.

Notes: If reflow temperatures exceed the recommended profile, devices may not meet the performance requirements.

Product Dimensions

Dimension	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.098	0.114	2.50	2.90
B	0.188	0.208	4.80	5.28
C	0.055	0.062	1.40	1.60
D	0.157	0.181	4.00	4.60
E	0.030	0.060	0.76	1.52
F	0.078	0.096	2.00	2.44
H	0.080	0.104	2.051	2.643



Summary of Packing Options

Package Type	Description	Packing Quantity	Industry Standard
DO-214AC(SMA) 	Embossed Carrier Reel Pack	5000PCS	EIA-481-D